



Attorney Docket # 5367-146PUS

MS-AF

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Dominik EISERT et al.

Serial No.: 10/523,551

Filed: October 18, 2005

For: GaN-Based Radiation-Emitting Thin-Layered
Semiconductor Component

Examiner: Nguyen, Joseph H.
Group Art: 2815

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Mail Stop AF, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

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Rance J. Lieberman
Name of applicant, Attorney or Registered Representative

Signature

January 29, 2009
Date of Signature

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Commissioner for Patents
P.O. Box 1450
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AMENDMENT AFTER FINAL REJECTION

SIR:

In response to the Final Office Action dated October 29, 2008, please amend the above-identified application as follows:

Amendments to the Claims begin on page 2 of this paper.

Remarks/Arguments begin on page 10 of this paper.